STARPOWER

SEMICONDUCTOR

RD75FPJ180K6S

1800V/75A in one-package

General Description

STARPOWER Rectifier Diode Power Module provides ultra low conduction loss. They are designed for the applications such as SMPS.

Features

- Low forward voltage drop
- Small temperature coefficient
- High Surge Capacity
- Low inductance
- Isolated Copper Baseplate Using DBC Technology

Typical Applications

- Input bridge rectifier
- AC/DC motor control
- Power supply

Equivalent Circuit Schematic





Rectifier Diode

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Absolute Maximum Ratings T_C=25°C unless otherwise noted

Rectifier Diode

Symbol	Description	Value	Unit
V _{RRM}	Repetitive Peak Reverse Voltage	1800	V
V _{RSM}	Non-repetitive Peak Reverse Voltage	1900	V
I _{FAV}	Average Forward Current $T_{C}=85^{\circ}C$	75	Α
I _{FSM}	Surge Forward Current $V_R=0V_{,t_p}=10m_{,t_1}=25^{\circ}C$	2625	٨
	$V_{R}=0V, t_{p}=10ms, T_{i}=125 °C$	2100	A
I ² t	I^2 t-value $V_R=0V, t_p=10ms, T_1=25^{\circ}C$	34453	Λ^2
	$V_{R}=0V_{t_{p}}=10ms, T_{1}=125^{\circ}C$	22050	AS

Thyristor

Symbol	Description	Value	Unit
V _{RRM}	Repetitive Peak Reverse Voltage	1800	V
V _{RSM}	Non-repetitive Peak Reverse Voltage	1900	V
I _{TAV}	Average On-state Current $T_C = 80^{\circ}C$	75	Α
т	Surge Forward Current $V_R=0V_{,t_p}=10m_{,t_j}=25^{\circ}C$	1680	٨
I _{TSM}	$V_{R}=0V_{t_{p}}=10ms_{t_{j}}=125^{\circ}C$	1522	A
I ² t	I^2 t-value $V_R=0V_{,t_p}=10$ ms, $T_j=25^{\circ}$ C	14112	Λ^2
	$V_{R}=0V, t_{p}=10ms, T_{j}=125^{\circ}C$	11582	AS
(di/dt)cr	Critical Rate of Rise of On-state Current	150	A /ug
	$T_j=125^{\circ}C$	150	A/µs
(dv/dt)cr	Critical Rate of Rise of On-State Voltage	1000	V/ue
	$T_i = 125^{\circ}C$	1000	v/µs

Module

Symbol	Description	Value	Unit
T _{jmax}	Maximum Junction Temperature	150	°C
T _{jop}	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature Range	-40 to +125	°C
V _{ISO}	Isolation Voltage RMS,f=50Hz,t=1min	4000	V

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
\mathbf{V}_{F}	Diode Forward	I _F =300A	$T_i = 25^{\circ}C$			1.55	V
	Voltage		T _j =125°C			1.50	
I _R	Diode Reverse Current	V _R =V _{RRM}	T _j =125°C			4.50	mA

Rectifier Diode $T_C=25^{\circ}C$ unless otherwise noted

Thyristor Diode T_C=25°C unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
V	Forward Voltage	I _T =300A	$T_j=25^{\circ}C$			1.90	V
ν _T			T _j =125°C			1.85	v
т	Reverse Current	V _R =V _{RRM}	T _i =25°C			0.05	
I_{D}			$T_j=125^{\circ}C$			10.0	ША
V _{GT}	Gate Trigger Current	$V_{\rm D} = 12 V_{,} T_{\rm j} = 25^{\circ} C$				1.5	V
I _{GT}	Gate Trigger Voltage	$V_{\rm D}$ =12V, $T_{\rm j}$ =25	5°C	10		80	mA
V _{GD}	Gate Non-trigger	$T = 125^{\circ}C$		0.25			V
	Current	1_{j} - 125 C		0.23			v
I _H	Holding Current	$T_j = 25^{\circ}C$				150	mA
IL	Latching Current	$I_{G}=1.2I_{GT}, T_{j}=$	25°C			200	mA

Module Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Min.	Тур.	Max.	Unit	
р	Junction-to-Case (per Rectifier)			0.434	V/W	
K _{th} JC	Junction-to-Case (per Thyristor)			0.296	К / W	
R _{thCH}	Case-to-Heatsink (per Rectifier)		0.336			
	Case-to-Heatsink (per Thyristor)		0.229		K/W	
	Case-to-Heatsink (per Module)		0.045			
М	Terminal Connection Torque, Screw M5		27		N.m	
	Mounting Torque, Screw M5		2.1			
G	Weight of Module		150		g	

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Diode Module

Circuit Schematic



Package Dimensions

Dimensions in Millimeters





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